

<u> **BatteryDirect**</u>™

Le87220 Worldwide xDSL Dual Channel Line Driver BD870 Series

APPLICATIONS

- Asymmetrical Digital Subscriber Loop (ADSL, ADSL+, ADSL2, ADSL2+) Line Drivers
- Glite Line Drivers
- HDSL, HDSL2, HDSL4, SHDSL Line Drivers
- DSLAM, CO, DLC, BLC, MDU/MTU Line Drivers

FEATURES

- Two-channel differential line drivers
- Low power
 - 720 mW per channel, typical (ADSL+ Mode) (showtime, >5 kft 26 AWG cable, not including load)
 - 670 mW per channel, typical (ADSL Mode) (showtime, >5 kft 26 AWG cable, not including load)
- Operates directly from a typical telecom power supply without a DC-to-DC converter and a 3.3 V supply
- Integrated lightning and surge protection
- 50 V_P differential signal at the driver outputs
- I_{OUT} max 95 mA into 100-Ω load
- MTPR of 70 dB, typical
- Minimum external component count ~ 10 discretes per channel
- Can output 20.8 dBm power into 100-Ω load with step down transformer
- Thermal shutdown
- Small footprint
 - 24-pin (6 x 6 mm) QFN

RELATED LITERATURE

080791 Quad Flat No-Lead (QFN) Package Application Note

ORDERING INFORMATION

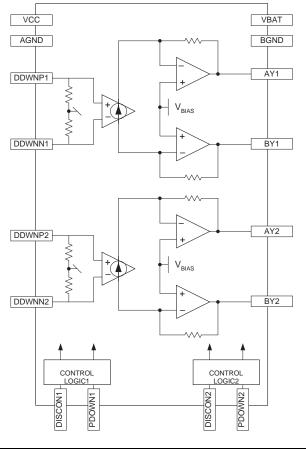
Device	Package	Packing ²
Le87220JQC	24-pin QFN, 6 x 6 mm	
Le87220KQC	24-pin QFN, 6 x 6 mm (Green Package) ¹	Tray

- The green package meets RoHS Directive 2002/95/EC of the European Council to minimize the environmental impact of electrical equipment.
- 2. For delivery using a tape and reel packing system, add a "T" suffix to the OPN (Ordering Part Number) when placing an order.

DESCRIPTION

The Le87220 device, from the Zarlink Battery Direct[™] family BD870 series devices, integrates two fully differential line drivers, optimized feed back components, on-chip surge protection diodes and bias control stages into a small 6 x 6 mm² QFN package. It contains all the active components needed to implement ADSL2+ downstream transmitters for two lines. The Le87220 device is built on Zarlink's high-voltage process that allows for direct operation from a standard telecom, negative battery supply (and a 3.3-V supply). In contrast, typical line cards today supply the power to the line drivers locally, via DC-to-DC converter modules. The elimination of these additional modules translates into cost and power savings at the system level. Operation from a centralized source of power makes the Le87220 device a unique, less costly, more efficient solution for xDSL line driver applications. The Le87220 device is one of the most costeffective and easy-to-use parts for today's xDSL applications.

BLOCK DIAGRAM



 Document ID#
 081111
 Date:
 Sep 20, 2007

 Rev:
 C
 Version:
 2

 Distribution:
 Public Document
 4

TABLE OF CONTENTS

Applications1
Features1
Related literature
Ordering Information
Description1
Block Diagram
Product Description
Lightning and Power Surges
Block Description
Downstream Path
Control Logic
Device Operating Modes
Active Mode
PDown Mode
Disconnect Mode
Operating Mode Control Decoding
Connection Diagram
Pin Descriptions
Absolute Maximum Ratings
Thermal Resistance
Package Assembly
Operating Ranges
Electrical Characteristics
Supply Currents and Power Consumption6
Test Circuit
Specifications
Device Specifications
Application Circuit
PCB Layout
Physical Dimensions
24-Pin QFN
Device Operational Notes
Power Supplies
Line Transformer
Transformer Turns Ratio
Downstream Filtering
Receiver and Hybrid Circuit
Components Selection
Revision History
Revision A1 to B1
Revision B1 to C1
Revision C1 to C2

PRODUCT DESCRIPTION

The Le87220 device is a low-power, dual xDSL differential line driver. It is part of Zarlink's family of integrated line drivers capable of operating from a standard negative battery supply. Its integration of feedback components and on-chip surge protection diodes makes it one of the most integrated line drivers on the market today.

The Le87220 device was designed on a high voltage, high bandwidth bipolar process in which fast slew rate and low distortion amplifiers were implemented. It requires one line transformer per line for isolation and for compliance with IEC60950-1, 2001 and UL60950 standards. The line driver amplifiers in the Le87220 device were designed with an optimized bandwidth for xDSL applications as well as for fast slew rates of 300 V/ μ s.

Lightning and Power Surges

The Le87220 device has built-in lightning and power surge protection. When used with the components listed in the <u>PCB Layout</u>. on page 8, it needs no other external protector to meet the requirements for ADSL line Cards.

Block Description

Refer to the datapath provider for the application circuit.

Downstream Path

The downstream signal is applied at the DDWNP/DDWNN pins, and is amplified by a fixed voltage gain (K_{DWN}) before being applied to the AY and BY pins. The amplifiers driving the AY and BY pins are DC biased to approximately one-half of the VBAT pin voltage. The typical differential output voltage swing between AY and BY pins is |VBAT| - 4 V. This allows the use of a step-down transformer for the line interface.

Control Logic

This block controls the bias currents of the input stage and the bias current of the output amplifiers as described in the *Device Operating Modes* section below.

DEVICE OPERATING MODES

The two lines of the Le87220 are completely independent and can be programmed to be in different operating modes. The logic signal level of pins DISCON1 an Pdown1 controls the operating mode of line 1, the logic signal level of pins DISCON2 and Pdown2 controls the operating mode of line 2.

Active Mode

In this mode, all stages are biased and operational.

PDown Mode

In this mode, the line driver amplifier's power consumption is reduced. The Bias current in the output stage drops to almost half full power stage. The part is ADSL compliant in this stage.

Disconnect Mode

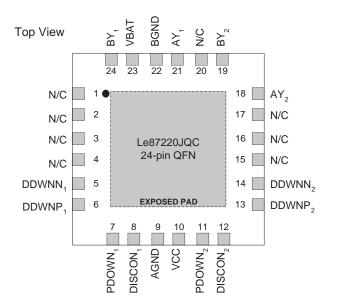
In this mode, the bias is turned OFF to all stages to save power. The device is not operational.

Operating Mode Control Decoding

DISCON ₁	Pdown ₁	Line 1 Operating Mode
0	0	Active
0	1	Pdown
1	х	Disabled

DISCON ₂	Pdown ₂	Line 2 Operating Mode
0	0	Active
0	1	Pdown
1	х	Disabled

CONNECTION DIAGRAM



Notes:

- 1. Pin 1 is marked for orientation.
- 2. The Le87220 device incorporates an exposed die pad on the underside of its package. The pad acts as a heat sink and must be connected to a copper plane through thermal vias, for proper heat dissipation (See PCB Layout, on page 8.).

PIN DESCRIPTIONS

Pin	Pin Name	Туре	Description
Pdown ₁ , Pdown ₂	Control Bits	Input	Active/Pdown mode control bit.
DDWNP ₁ , DDWNN ₁ , DDWNP ₂ , DDWNN ₂	Differential Downstream	Input	The differential downstream signal from the data AFE is AC coupled to these pins.
DISCON ₁ , DISCON ₂	Disconnect	Input	Disables the line completely by pulling it to VCC.
AY ₁ , BY ₁ AY ₂ , BY ₂	A/B Line Driver	Output	Differential downstream line driver outputs.
VBAT	Negative Battery	Power	Negative power supply.
VCC	Power Supply	Power	+3.3 V analog power supply.
AGND	Analog Ground	Ground	Low voltage ground return.
BGND	Battery Ground	Ground	Battery ground return.
N/C	No Connect		Not connected.
EXPOSED PAD		Isolated	Exposed pad on underside of device must be connected to a heat spreading area. The AGND plane is recommended.

ABSOLUTE MAXIMUM RATINGS

Stresses above the values listed under *Absolute Maximum Ratings* can cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods can affect device reliability.

Storage Temperature	$-55 \le T_A \le +150^{\circ}C$
Ambient temperature, under bias	$-40 \le T_A \le +85^\circ C$
V_{CC} with respect to AGND	A
	–0.4 V to +6 V
V _{BAT} with respect to BGND	+0.4 V to -75 V
BGND with respect to AGND (1 ms)	-5.5 V to +0.2 V
Maximum Current into AY, BY	
Continuous	±200 mA
100 μs (F = 0.1 Hz)	±1 A
1 μs (F = 0.1 Hz)	±2.5 A
250 ns (F = 0.1 Hz)	±5.5 A
Peak current output, AY or BY pins	±200 mA
Pdown, DISCON pins with respect to AGND	-0.4 V to (V _{CC} + 0.4 V)
Maximum Power Dissipation, T _A = 85°C	2 W
(See Notes 1 and 2)	2 **
ESD Immunity (Human Body Model)	JESD22 Class 1C compliant
ESD Immunity (Charge Device Model)	Class C6 1500 - 2000 V

Notes:

- 1. Thermal limiting circuitry on chip will shut down the circuit at a junction temperature of about 165°C. Continuous operation above 145°C junction temperature may degrade device reliability.
- The thermal performance of a thermally enhanced package is assured through optimized printed circuit board layout. Specified performance requires that the exposed thermal pad be soldered to an equally sized exposed copper surface, which, in turn, conducts heat through multiple vias to a large internal copper plane (See PCB Layout, on page 8.).

Thermal Resistance

The junction to air thermal resistance of the Le87220 device in a 24-pin QFN package is 30°C/W (measured with infinite external heat sinking). Please refer to Zarlink's *QFN Package* application note, available from http://www.zarlink.com____, for layout and heat sinking guidelines.

Package Assembly

The standard (non-green) package devices are assembled with industry-standard mold compounds, and the leads possess a tin/ lead (Sn/Pb) plating. These packages are compatible with conventional SnPb eutectic solder board assembly processes. The peak soldering temperature should not exceed 225°C during printed circuit board assembly.

The green package devices are assembled with enhanced, environmental compatible lead-free, halogen-free, and antimony-free materials. The leads possess a matte-tin plating which is compatible with conventional board assembly processes or newer lead-free board assembly processes. The peak soldering temperature should not exceed 245°C during printed circuit board assembly.

Refer to IPC/JEDEC J-Std-020B Table 5-2 for the recommended solder reflow temperature profile.

OPERATING RANGES

Zarlink guarantees the performance of this device over commercial (0°C to 70°C) and industrial (-40°C to 85°C) temperature ranges by conducting electrical characterization over each range and by conducting a production test with single insertion coupled with periodic sampling. These characterization and test procedures comply with section 4.6.2 of Bellcore GR-357-CORE Component Reliability Assurance Requirements for Telecommunications Equipment.

Ambient temperature	-40°C to +85°C
V _{CC}	+3.3 V ± 5%
V _{BAT}	-42 V to -72 V
BGND with respect to AGND	-2 to +0.1VDC

The Le87220 is designed to operate with a standard telecom battery. The normal operating voltage of such batteries is -52 V, and the Le87220 is designed to give optimal performance in terms of power dissipation if used with the provided applications circuit. However, because the Le87220 is designed on Zarlink's proprietary high voltage, high bandwidth process, the part will continue to remain in operation without any degradation in data performance should the battery drop to as low as -42 V, or charge to as high as -72 V. Should there be a need to operate the part continuously at such voltages, a different applications circuit should be considered to achieve best power performance. Lower voltage operation can be achieved by adding a buck-boost regulator.

The Le87220 is designed to operate with the T1.315 specified telecom battery, without any need for changes in the reference design.

ELECTRICAL CHARACTERISTICS

 V_{BAT} = -52 V, V_{CC} = +3.3 V, T_A = 25°C unless otherwise specified.

Supply Currents and Power Consumption

Values listed in the table below are per line, and include the load power.

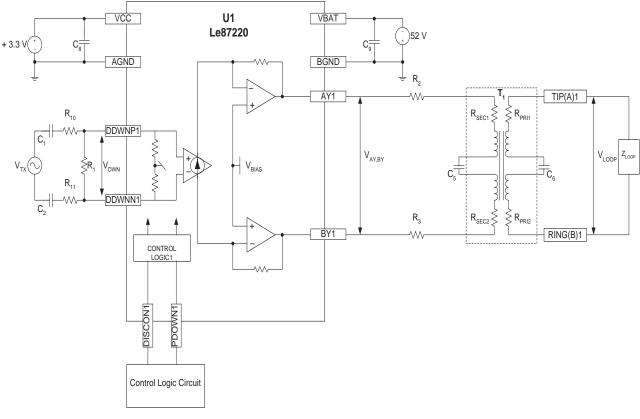
Operational			V _{BAT} (mA) V _{CC} (mA)		A)	Device Power (mW)						
State	Condition	T _A	Min	Тур	Мах	Min	Тур	Мах	Min	Тур	Max	Note
	Training at 5 kft 26 AWG cable	25°C		16			5.3			850		
Active	Showtime at 5 kft 26 AWG cable, 19.85 dBm	25°C		15.5			5.3			824		
Active	19.85 dBm signal into 100 Ω load	25°C		15.5			5.3			824		
	with 2.45:1 transformer	Full range		15.5			5.6			826		<u>1.</u>
		25°C		14.5			5.3			772		
Pdown		Full range		14.5			5.3			772		
Disconnect		Full range		1			5.3			65		

Note:

1. In the Active state, 96.6 mW is dissipated in the loop and 7.5 mW is dissipated in the transformer plus the series drive resistors. For device power dissipation, subtract these values from the numbers listed in the table above.

TEST CIRCUIT

Only one of two channels is shown.



Note:

1. Component values are the same as those listed in the <u>PCB Layout</u>, on page 8 unless otherwise noted.

SPECIFICATIONS

Device Specifications

Typical Conditions: V_{BAT} = -52 V, V_{CC} = 3.3 V, Transformer Turns Ratio = 2.45:1

Min/Max Parameters: T = -40 to +85°C; Typ, TA = 25°C

Note:

Parameters in the following "Device Specifications" tables are guaranteed by characterization. Refer to Test Circuit. on page 6.

Table 1. Pdown = 0 (Full Power)

Specification	Condition		Min	Тур	Max	Unit	Note
		AC Characterist	ics				
Vn _{DWN}	Output Differential Noise V at (AY, BY) V _{TX} =0 V, 25 kHz to 2208 k	-		0.6	1.0	$\frac{\mu V}{\sqrt{Hz}}$	
R _{DDWN}	Differential Input Impedant	ce DDWNP to	28k	40k	52k	kΩ	
V _{AYDC} , V _{BYDC}	AY, BY DC bias voltage		$\frac{V_{BAT}}{2} - 0.25$	$\frac{V_{BAT}}{2} + 0.75$	$\frac{V_{BAT}}{2} + 1.75$	V	
	VCC to AY, BY	20 kHz	-38				
PSRR _{VCC}	All operating Modes	400 kHz 800 kHz	-26				
	All operating modes	2 MHz	-24				
		2 1011 12	-20				
	VBAT to AY, BY	20 kHz	-50				
PSRR _{VBAT}	All operating Modes	400 kHz 800 kHz	-44			dB	
		2 MHz	-37				
		2 1011 12	-32			-	
	BGND to AY, BY	20 kHz	-50				
PSRR _{BDND}	All operating Modes	400 kHz 800 kHz	-50 -50				
	, an operating mease	2 MHz	-50 -50			-	
	Xtalk fc=100 kH	Iz, Vout=2Vpp	_30 70	80			
Crosstalk between lines		Hz, Vout=2Vpp	50	60		dB	<u>1., 2.</u>
V _{IN, DWN}	Input Amplitude, AC coupl				1.0	V	
lout, max	lout max into 100 ohm loa				95	mA	
	Pdown2, DISCON1 and DIS						
V _{IH}	Logic 1, High level Input v	,	2		VCC		
V _{IL}	Logic 0, Low level Input vo	-	AGND		0.8	V	
I _{IH}	Pdown = VCC	Jildge			100		
۰۱۲ ار	Pdown = AGND				-100		
	DISCON = VCC					μA	
I _{IH}					100		
I	DISCON = AGND	Decise Decise			-100		
0	Slew Rate at V _{AY–BY}	Device Performa		000			.
S _R			250	300		V/µs	
HD2	fc=1MHz, RL=100Ohms, Vou			-70		dBc	
HD3	fc=1MHz, RL=100Ohms, Vout Downstream multitone pov			-70		dBc	<u>3.</u>
MTPR	G.992.1 MTPR test peak t		70		dB		
K _{DWN}	K _{DWN} = V _{AY,BY} /V _{DWN} 25 kHz to 2208 kHz	46	48	50	V/V		
K _{DWN} vs. frequency	-3 dB		5			MHz	

Specification	Condition	Min	Тур	Max	Unit	Note		
AC Characteristics								
Vn _{DWN}	Output Differential Noise Voltage, at (AY, BY) V _{TX} =0 V, 25 kHz to 1104 kHz		0.6	1.0	$\frac{\mu V}{\sqrt{Hz}}$			
R _{DDWN}	Differential Input Impedance DDWNP to DDWNN	28k	40k	52k	kΩ			
V _{AYDC} , V _{BYDC} AY, BY DC bias voltage		$\frac{V_{BAT}}{2} - 0.25$	$\frac{V_{BAT}}{2} + 0.75$	$\frac{V_{BAT}}{2} + 1.75$	V			
Crosstalk	Xtalk fc=100 kHz, Vout=2Vpp	70	80			4 0		
between lines	fc=1104 kHz, Vout=2Vpp	50	60		dB	<u>1., 2.</u>		
V _{IN, DWN}	Input Amplitude, AC coupled			1.0	V			
lout, max	lout max into 100 ohm load			80	mA			
	Device Perform	nance						
S _R	Slew Rate at V _{AY-BY}	200	250		V/µs			
HD2	fc=1MHz, RL=100Ohms, Vout=2Vp-p		-67.5		dBc			
HD3	fc=1MHz, RL=100Ohms, Vout=2Vp-p		-67.5		dBc	<u>3.</u>		
MTPR	TPR Downstream multitone power ratio ITU, G.992.1 MTPR test peak to rms ratio = 5.8		67.5		dB	<u>v.</u>		
K _{DWN}	$K_{DWN} = V_{AY,BY}/V_{DWN}$ 25 kHz to 1104 kHz	46	48	50	V/V			
K _{DWN} vs. frequency	-3 dB	4			MHz			

Table 2. Pdown = 1 (Power Down)

Notes:

1. Crosstalk is measured with one line transmitting signal, the other line is enabled but V_{TX} is set to 0 V.

2. Crosstalk: Xtalk(dB) =
$$20\log\left(\frac{V(AY, BY)1}{V(AY, BY)2}\right)$$

3. Measured with a 2.45:1 transformer and a $100-\Omega$ load.

APPLICATION CIRCUIT

Refer to the datapath reference design.

PCB Layout

The Le87220 device contains high gain and high bandwidth amplifiers. The amplifier inputs of each line are connected to the DDWNP/DDWNN pins, the output are connected to the AY and BY pins. To prevent coupling of the high level output signals into the low level DDWNP/DDWNN pins, PCB tracks and components connected to AY, BY, and going to the TIP (A) and RING (B) terminals must be well separated from tracks connected to DDWNP/DDWNN pins. The components C1, C2, R1, R10, and R11 (and the corresponding components of line 2) should be as close as practical to DDWNP/DDWNN pins. The Le87220 device provides an analog ground pin (AGND) as a return for low level currents and a battery ground pin (BGND) as a return for high level currents.

The differential drivers of the Le87220 device do not produce any load current into the AGND leads, but the amplifier currents are still circulating in the VBAT and BGND pins. A bypass capacitor between VBAT and BGND is required to be close to the device. AGND and BGND tracks should only be tied together at a single point, close to the power connector of the card.

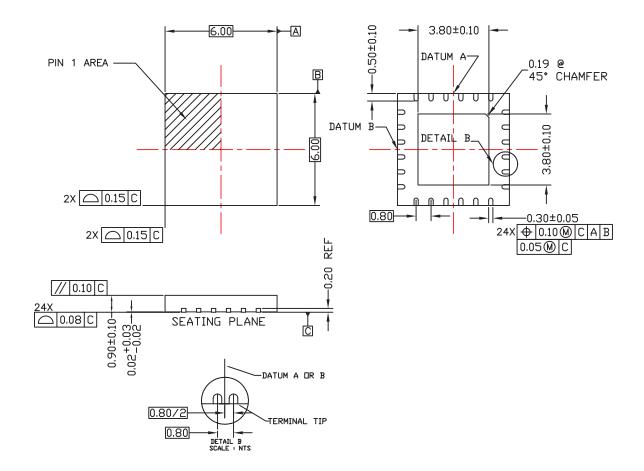
The Le87220 device uses a thermally enhanced package equipped with an exposed pad on the bottom side. The printed circuit board surface must have a copper pad covering the full surface of the thermal pad. The copper pad must be fitted with a minimum of 16 thermal transfer vias on a 1 mm pitch with a via diameter of 0.3 to 0.33 mm, and be connected to a large internal copper plane for proper heat dissipation. The AGND plane is recommended. The thermal transfer vias should be connected to the thermal pad and to the AGND plane without thermal relieve tracks. The AGND plane should be the second layer from the top of the PCB for the best power dissipation.

In multi-line applications, the Le87220 devices must be positioned in the layout to ensure a minimum distance of 1 inch (center to center) between devices. Passive non-heat producing components can be placed between the Le87220 devices.

PHYSICAL DIMENSIONS

24-Pin QFN

24 Lead QFN with Chamfer



Symbol	24 LEAD QFN					
Symbol	Min	Nom	Max			
Α	0.80	0.90	1.00			
A2	().57 RE	F			
b	0.18	0.23	0.38			
D	6	6.00 BS	С			
D2	3.70	3.80	3.90			
E	6.00 BSC					
E2	3.70	3.80	3.90			
е	().80 BS(0			
L	0.30	0.40	0.50			
N		24				
A1	0.00	0.02	0.05			
A3	0.20 REF					
aaa	0.15					
bbb	0.10					
ccc		0.10				

NOTES:

- 1. Dimensioning and tolerancing conform to ASME Y14.5M-1994.
- 2. All dimensions are in millimeters. \oplus is in degrees.
- 3. N is the total number of terminals.
- A The Terminal #1 identifier and terminal numbering convention shall conform to JEP 95-1 and SSP-012. Details of the Terminal #1 identifier are optional, but must be located within the zone indicated. The Terminal #1 identifier may be either a mold or marked feature.
- S Coplanarity applies to the exposed pad as well as the terminals.
- 6. Reference Document: JEDEC MO-220.

Note:

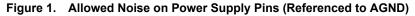
Packages may have mold tooling markings on the surface. These markings have no impact on the form, fit or function of the device. Markings will vary with the mold tool used in manufacturing.

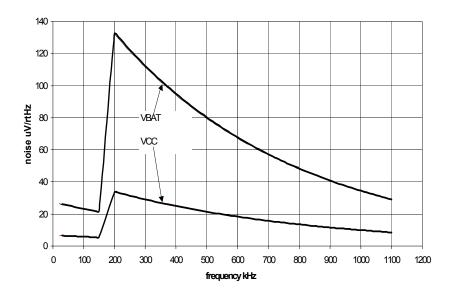
DEVICE OPERATIONAL NOTES

Power Supplies

The Le87220 device is implemented in a high-voltage process that allows direct powering from the -42 V to -72 V battery supply without the need for DC to DC converters. This saves significant power that would otherwise be wasted in the DC to DC converter.

The noise on (referenced to AGND) the battery supply (VBAT pin) and on the +3.3 V supply (VCC pin) should be below the limits as shown in Figure 1, in order not to affect the data performance.





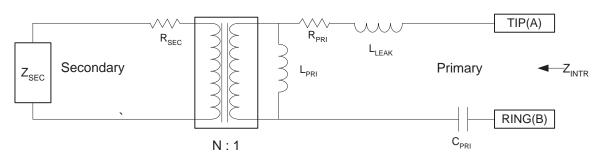
Line Transformer

A step-down transformer is used to interface the Le87220 device with the TIP (A) and RING (B) line terminals. The transformer injects the data signal onto the loop and provides dielectric isolation and impedance matching between the loop and the line driver. The turn ratio of the transformer can be optimized to match the loop signal level to the driver output swing (see <u>Transformer Turns</u> <u>Ratio, on page 11</u>).

Transformer Specifics

Figure 2 represents a simplified transformer model in which the boxed block is an ideal transformer with an infinite bandwidth.

Figure 2. Le87220 Transformer



Transformer Turns Ratio

The transformer turns ratio N is restricted by the maximum peak differential signal at AY/BY pins, which must stay within the Le87220 device's dynamic range. The output voltage range is typically equal to $|V_{BATmin}| - 4 V$.

The maximum peak voltage (across 100 Ω at TIP (A) and RING (B) leads of a FDM ADSL signal using 224 downstream carriers for a combined rms power of 19.85 dBm and a peak-to-rms ratio of 5.8) is 36.05 V_{PP} differential. To account for the voltage drop across Z_{SEC}, this voltage must be scaled up by a factor of 1.086. The required peak differential signal at the AY/BY pins would be 39.15 V_{PP} or 19.6 V_{PP} per driver if the transformer had a 1:1 turn ratio. Using this information the transformer turns ratio can be calculated as

$$\mathsf{N} = \frac{|\mathsf{V}_{\mathsf{BAT}}| - 4\mathsf{V}}{19.6\mathsf{V}}$$

The transformer turns ratio for a nominal battery voltage of -52 V is then N=2.45:1.

The Le87220 device is designed to operate with battery voltage in the range of -42 V to -72 V. The data transformer turns ratio can be optimized for the specific battery voltage range, but the turns ratio must be limited to less than 2.7:1 secondary to primary (where the primary side is connected to TIP (A) and RING (B)) if 19.85 dBm needs to be produced at the output. This limitation is imposed by the Le87220 device internal bias levels.

Downstream Filtering

The input differential impedance (R_{DDWN}) of the DDWNP/DDWNN pins can vary by as much as ± 30%, and consequently a lower value external resistor R_1 is used to set the differential input impedance (refer to the data path reference design).

A high-pass filter with a -3 dB corner frequency of

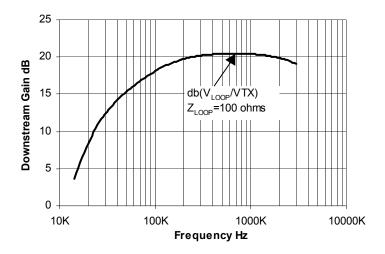
$$f_{\text{DWNHPF}} = \frac{1}{2\pi R_{\text{IN}} C_{\text{IN}}}$$

is formed by C_1 and C_2 in conjunction with R_{IN} to attenuate the low frequency noise of the downstream signal where

$$R_{IN} = R_{10} + R_{11} + (R_1 || R_{DDWN})$$
$$C_{IN} = \frac{C_1 \cdot C_2}{C_1 + C_2}.$$

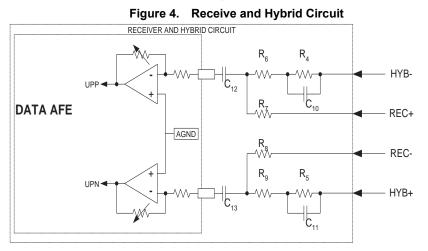
In addition to rejecting the low frequency signals from the data AFE, the input capacitors also block DC currents from flowing between DDWNP/DDWNN and the data AFE outputs. With the recommended R₁ value of 5.49 k Ω , R₁₀ = R₁₁ = 2.67 k Ω and C₁ = C₂ = 1.5 nF provides a corner frequency of around 25 kHz. Resistors R₁₀, R₁₁ and R₁ can be used to adjust the downstream signal level.

Figure 3. Downstream Gain of the Application Circuit. on page 8



RECEIVER AND HYBRID CIRCUIT

The receive and hybrid circuit architecture depends greatly on the data AFE being used in the design. Some data AFEs have built-in input differential amplifiers for the receive circuits. These amplifiers should be used to implement the receive and hybrid functions. If the AFE does not have such amplifiers, then external low noise amplifiers are required to implement these functions. Figure 4 shows a typical implementation of the receive and hybrid functions.



COMPONENTS SELECTION

The DC blocking capacitor C_6 is required on the primary or line side of the transformer in order to avoid applying a DC short across TIP (A) and RING (B) terminals. The value of the line side capacitor depends on transformer primary inductance chosen to give desired –3 dB high pass point. According to T1.413, the impedance measured across TIP (A) and RING (B) at 4 kHz must be greater than 1100 Ω , which requires a capacitance of less than 35 nF for the series combination of C₆ and any external DC blocking capacitor.

The minimum transformer primary inductance required is dictated by the low end of the upstream frequency band, which is typically around 25-30 kHz. Since the transformer primary inductance shunts the line, it should be relatively high to avoid signal attenuation and maintain an acceptable match across the desired bandwidth. A high impedance can be obtained by using a transformer with a high primary side inductance while maintaining relatively low DC resistance for minimum insertion loss. Besides using it for its isolation and high common-mode rejection it is also used as part of the high-pass splitter function. If the -3 dB point is chosen to be around 20 kHz, the minimum primary (line side) inductance required would be

$$L_{PRI} = \frac{|Z_{LOOP}|}{2\pi(20 \text{ kHz})} = \frac{100}{2\pi(20 \text{ kHz})} \approx 796 \text{ }\mu\text{H} .$$

For the Le87220 device, a transformer primary side inductance of >800 μ H is recommended

REVISION HISTORY

Revision A1 to B1

Removed 8 x 8 QFN package data

Revision B1 to C1

- Added OPN for green package in <u>Ordering Information, on page 1</u>
- Added column and note to <u>Ordering Information</u>, on page 1 to indicate packing system
- Revised 24-lead QFN drawing in <u>Physical Dimensions</u>, on page 9 to show chamfer

Revision C1 to C2

- Enhanced format of package drawing in *Physical Dimensions*, on page 9
- Added new headers/footers due to Zarlink purchase of Legerity on August 3, 2007



For more information about all Zarlink products visit our Web Site at

www.zarlink.com

Information relating to products and services furnished herein by Zarlink Semiconductor Inc. or its subsidiaries (collectively "Zarlink") is believed to be reliable. However, Zarlink assumes no liability for errors that may appear in this publication, or for liability otherwise arising from the application or use of any such information, product or service or for any infringement of patents or other intellectual property rights owned by third parties which may result from such application or use. Neither the supply of such information or purchase of product or service conveys any license, either express or implied, under patents or other intellectual property rights owned by Zarlink or licensed from third parties by Zarlink, whatsoever. Purchasers of products are also hereby notified that the use of product in certain ways or in combination with Zarlink, or non-Zarlink furnished goods or services may infringe patents or other intellectual property rights owned by Zarlink.

This publication is issued to provide information only and (unless agreed by Zarlink in writing) may not be used, applied or reproduced for any purpose nor form part of any order or contract nor to be regarded as a representation relating to the products or services concerned. The products, their specifications, services and other information appearing in this publication are subject to change by Zarlink without notice. No warranty or guarantee express or implied is made regarding the capability, performance or suitability of any product or service. Information concerning possible methods of use is provided as a guide only and does not constitute any guarantee that such methods of use will be satisfactory in a specific piece of equipment. It is the user's responsibility to fully determine the performance and suitability of any equipment using such information and to ensure that any publication or data used is up to date and has not been superseded. Manufacturing does not necessarily include testing of all functions or parameters. These products are not suitable for use in any medical products whose failure to perform may result in significant injury or death to the user. All products and materials are sold and services provided subject to Zarlink's conditions of sale which are available on request.

Purchase of Zarlink's l2C components conveys a license under the Philips l2C Patent rights to use these components in an l2C System, provided that the system conforms to the l2C Standard Specification as defined by Philips.

Zarlink, ZL, the Zarlink Semiconductor logo and the Legerity logo and combinations thereof, VoiceEdge, VoicePort, SLAC, ISLIC, ISLAC and VoicePath are trademarks of Zarlink Semiconductor Inc.

TECHNICAL DOCUMENTATION - NOT FOR RESALE